## NSN 5961-01-296-8806

Unitized Semiconductor Devices - Page 1 of 1



View Online at https://aerobasegroup.com/nsn/5961-01-296-8806 **Inclosure Material:** Ceramic **Overall Length:** 0.925 inches **Terminal Length:** 0.190 inches **Overall Height:** 0.192 inches **Overall Width:** 0.480 inches **Component Name And Quantity:** 30 semiconductor device diode **Mounting Method: Terminal Features Provided:** Hermetically sealed case **Semiconductor Material:** Silicon all semiconductor device diode Voltage Rating In Volts Per Characteristic: 30.0 reverse voltage, dc all semiconductor device diode **Current Rating Per Characteristic:** 4.00 microamperes forward current, average peak all semiconductor device diode **Power Rating Per Characteristic:** 500.0 watts small-signal input power, common-collector major all semiconductor device diode **Capacitance Rating In Picofarads:** 165.0 all semiconductor device diode **Maximum Operating Tempurature Per Measurement Point:** 150.0 degrees celsius ambient air **Special Features:** All semiconductor device diode junction pattern arrangement: pn **Terminal Type And Quantity:** 16 pin Shelf Life: N/a **Unit Of Measure: Demilitarization:** No

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